

Abstracts

Systematic investigations on MESFETs and passive components transplanted by epitaxial lift off onto host materials with various resistivities (1997 [RFIC])

T. Morf, C. Biber and W. Bachtold. "Systematic investigations on MESFETs and passive components transplanted by epitaxial lift off onto host materials with various resistivities (1997 [RFIC])." 1997 Radio Frequency Integrated Circuits (RFIC) Symposium 97. (1997 [RFIC]): 197-200.

In this paper we present RF measurements on MESFETs and spiral inductors fabricated on GaAs and transplanted by epitaxial lift off (ELO). ELO is a technology by which epitaxially grown layers are lifted off from their growth substrate and are subsequently reattached to a new host substrate.

[Return to main document.](#)